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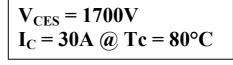


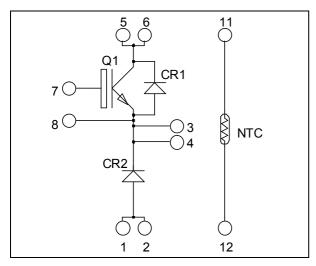


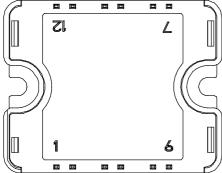




Buck chopper Trench + Field Stop IGBT3 Power Module







Pins 1/2; 3/4; 5/6 must be shorted together

Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

INDUITE	c maximum racings			
Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1700	V
т	Continuous Collector Current	$T_C = 25^{\circ}C$	45	
I_{C}	Continuous Collector Current	$T_C = 80^{\circ}C$	30	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	70	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	210	W
RBSOA	Reverse Bias Safe Operating Area	$T_{j} = 125^{\circ}C$	60A@1600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				250	μΑ
V _{CE(sat)}	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		2.0	2.4	V
		$I_C = 30A$ $T_j = 125$ °C		2.4		·	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1.5 \text{mA}$		5.2	5.8	6.4	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				600	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
Cies	Input Capacitance	$V_{GE} = 0V, V_{CE} =$	$V_{GE} = 0V, V_{CE} = 25V$		2500		pF	
C_{res}	Reverse Transfer Capacitance	f = 1MHz			90		pr.	
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			100			
T_{r}	Rise Time		$V_{GE} = \pm 15V$		70			
T _{d(off)}	Turn-off Delay Time	$V_{\text{Bus}} = 900V$ $I_{\text{C}} = 30A$			650		ns	
T_{f}	Fall Time	$R_G = 18\Omega$		80				
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 900V$ $I_{C} = 30A$			100			
T_{r}	Rise Time				70			
$T_{d(off)}$	Turn-off Delay Time				750		ns	
T_{f}	Fall Time	$R_G = 18\Omega$			100			
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 900V$	$T_j = 125$ °C		17		I	
E _{off}	Turn-off Switching Energy	$I_C = 30A$ $R_G = 18\Omega$	$T_j = 125^{\circ}C$		15		mJ	

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Test Conditions		Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1700			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1700V	$T_i = 25$ °C $T_i = 125$ °C			250 500	μΑ
I_{F}	DC Forward Current		$T_{\rm C}$ =80°C		50	300	A
$V_{\rm F}$	Diode Forward Voltage	$I_F = 50A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.8	2.2	V
V F	Diode Polward Voltage		$T_{i} = 125^{\circ}C$		1.9		v
+	Davana Daaayami Tima	$I_F = 50A$ $V_R = 900V$ $di/dt = 800A/\mu s$	$T_j = 25$ °C		385		ns
t _{rr}	Reverse Recovery Time		$T_j = 125$ °C		490		115
	Danier Danier Chama		$T_j = 25$ °C		14		C
Q_{rr}	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		23		μC
Е	D D E		$T_j = 25$ °C		6		ma T
E_{r}	Reverse Recovery Energy		$T_{j} = 125^{\circ}C$		12		mJ

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Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance	IGBT			0.60	°C/W	
IX _{th} JC		Diode			0.70	C/ W	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature -40					100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight	•	•			80	g

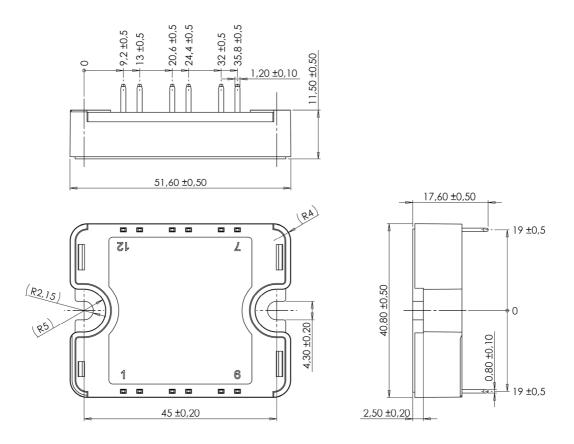
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B _{25/85}	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

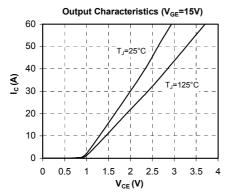
SP1 Package outline (dimensions in mm)

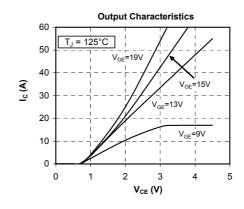


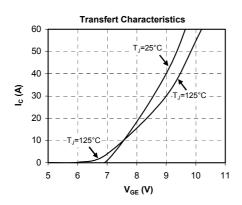
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

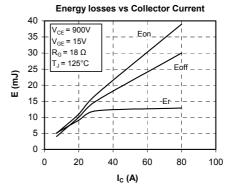


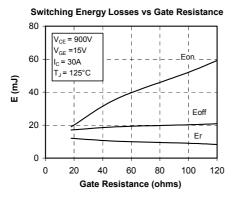
Typical Performance Curve

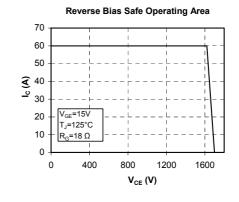


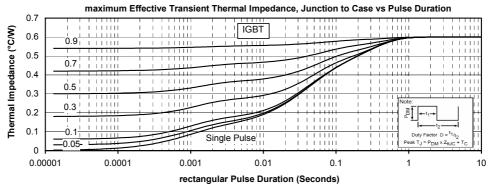




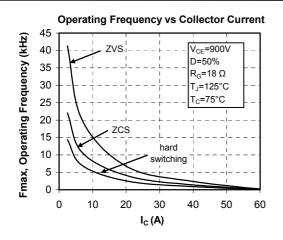


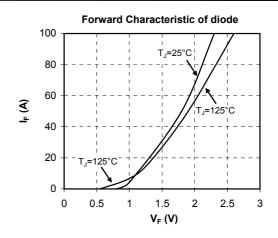


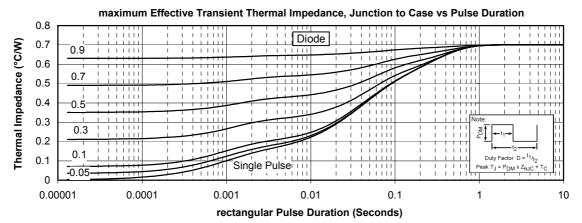












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